

**Docket No.:** 2336-255

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application of	:	
	:	
Seung Wan CHAE	:	Confirmation No. 2799
	:	
Application No. 10/812,015	:	Group Art Unit: 2811
	:	
Filed: March 30, 2004	:	Examiner: HUNG K VU

**For: GALLIUM NITRIDE (GaN)-BASED SEMICONDUCTOR LIGHT EMITTING DIODE  
AND METHOD FOR MANUFACTURING THE SAME**

**PETITION FOR EXTENSION OF TIME**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

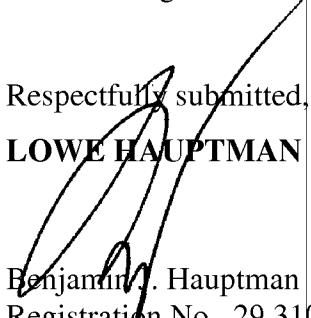
Dear Sir:

Applicant(s) hereby petition(s) the Commissioner of Patents and Trademarks to extend the time for response to the Official Action dated August 23, 2006 for 1 month from November 23, 2006 to December 23, 2006.

A credit card authorization form to cover the cost of the extension is attached. Any deficiency or overpayment should be charged or credited to Deposit Account No.: 07-1337.

Respectfully submitted,

**LOWE HAUPTMAN & BERNER, LLP**

  
Benjamin J. Hauptman  
Registration No. 29,310

1700 Diagonal Road, Suite 310  
Alexandria, Virginia 22314  
Telephone: (703) 684-1111  
Facsimile: (703) 518-5499  
**DATE: December 26, 2006**  
BJH:AYW